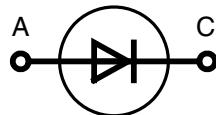


# Avalanche Diode

**V<sub>RRM</sub> = 1200-1800 V**  
**I<sub>F(RMS)</sub> = 18 A**  
**I<sub>FAVM</sub> = 11 A**

V <sub>RSM</sub> V	V <sub>(BR)min</sub> V	V <sub>RRM</sub> V	Type
1300	1300	1200	DSA 9-12F
1700	1750	1600	DSA 9-16F
1900	1950	1800	DSA 9-18F



DO-203 AA



A = Anode, C = Cathode

Symbol	Conditions	Maximum Ratings		
I <sub>FRMS</sub>	T <sub>VJ</sub> = T <sub>VJM</sub>	18	A	
I <sub>FAVM</sub>	T <sub>C</sub> = 150°C; 180° sine	11	A	
P <sub>RSM</sub>	T <sub>VJM</sub> , t <sub>p</sub> = 10 ms	4.5	kW	
I <sub>FSM</sub>	T <sub>VJ</sub> = 45°C; t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	250 265	A	
	T <sub>VJ</sub> = 150°C; t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	200 220	A	
I <sup>2</sup> t	T <sub>VJ</sub> = 45°C; t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	310 295	A <sup>2</sup> s	
	T <sub>VJ</sub> = 150°C; t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	200 190	A <sup>2</sup> s	
T <sub>VJ</sub>		-40...+180	°C	
T <sub>VJM</sub>		180	°C	
T <sub>stg</sub>		-40...+180	°C	
M <sub>d</sub>	mounting torque	2.2...2.8	Nm	
Weight	typical	5	g	

Symbol	Conditions	Characteristic Values		
		typ.	max.	
I <sub>R</sub>	V <sub>R</sub> = V <sub>RRM</sub> T <sub>VJ</sub> = T <sub>VJM</sub>		3	mA
V <sub>F</sub>	I <sub>F</sub> = 36 A      T <sub>VJ</sub> = 25°C		1.4	V
V <sub>T0</sub>	For power-loss calculations only	0.85		V
r <sub>T</sub>	T <sub>VJ</sub> = T <sub>VJM</sub>	15		mΩ
R <sub>thJC</sub>	DC current 180° sine	2		K/W
R <sub>thJH</sub>	DC current	2.17		K/W
d <sub>S</sub>	Creepage distance on surface	3.0		K/W
d <sub>A</sub>	Strike distance through air	2.0		mm
a	Max. allowable acceleration	100		m/s <sup>2</sup>

Data according to IEC 60747

## Features

- International standard package JEDEC DO-203 AA
- Planar passivated chips

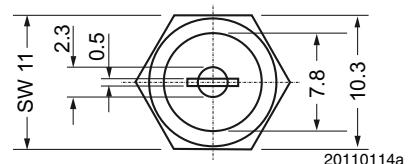
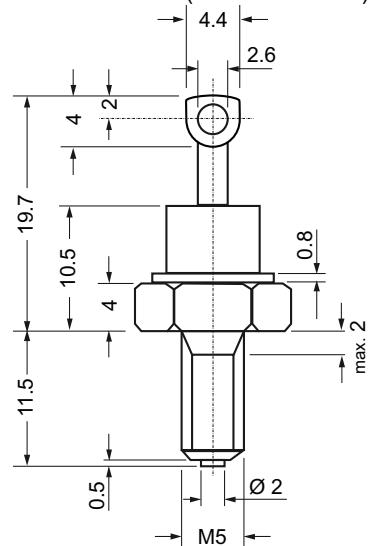
## Applications

- Supplies for DC power equipment
- DC supply for PWM inverter
- Field supply for DC motors
- Battery DC power supplies

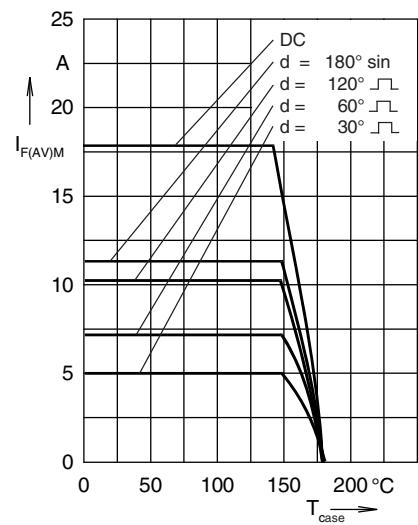
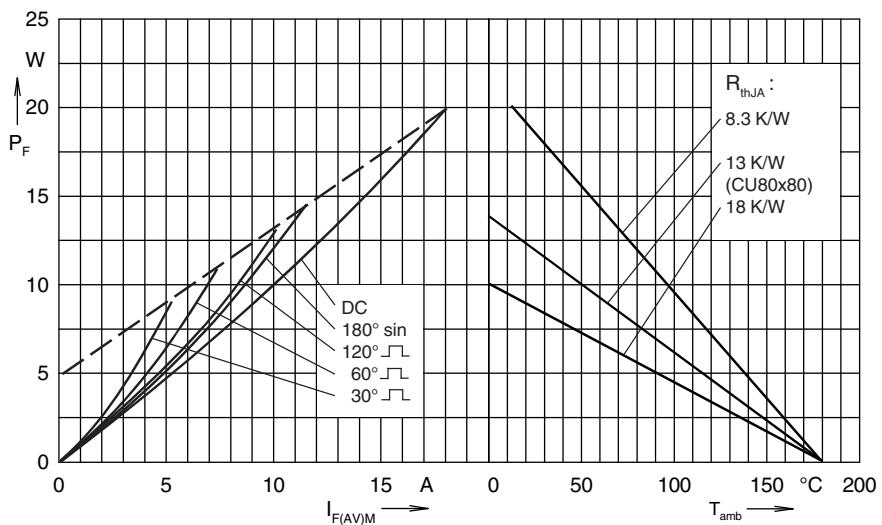
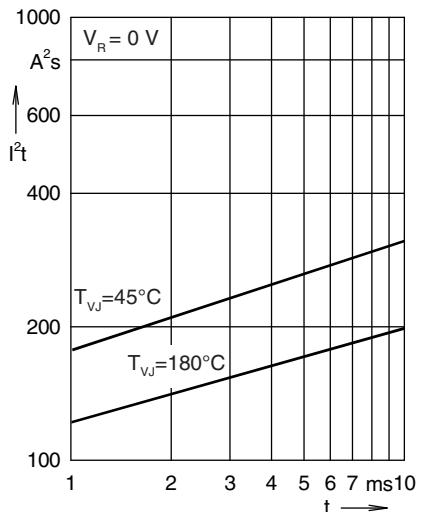
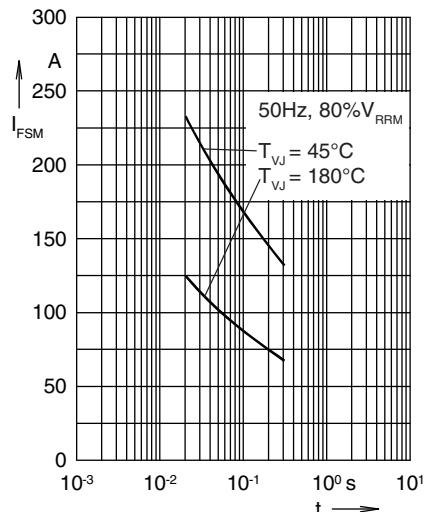
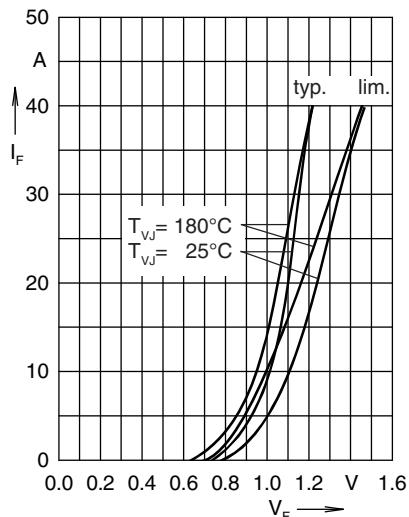
## Advantages

- Space and weight savings
- Simple mounting
- Improved temperature & power cycling
- Reduced protection circuits

Dimensions in mm (1 mm = 0.0394")



IXYS reserves the right to change limits, test conditions and dimensions.



$R_{thJH}$  for various conduction angles d:

d	$R_{thJH}$ (K/W)
DC	3.0
180°	3.35
120°	3.56
60°	4.0
30°	4.64

Constants for  $Z_{thJH}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.095	0.00032
2	0.515	0.0102
3	1.39	0.360
4	1.0	2.30

Fig. 6 Transient thermal impedance junction to heatsink